DISCRETE SEMICONDUCTORS





1PS10SB63 Schottky barrier diode

Product specification

2003 Aug 20







Schottky barrier diode

1PS10SB63

FEATURES

- · Very low diode capacitance
- · Low forward voltage
- Leadless ultra small plastic package (1.0 mm × 0.6 mm × 0.5 mm)
- Boardspace 1.17 mm² (approx. 10% of SOT23)
- Power dissipation comparable to SOT23.

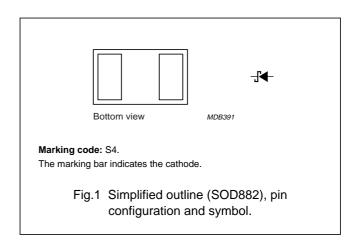
APPLICATIONS

- Ultra high-speed switching
- High frequency detection
- · Zero bias detection
- Mobile communication, digital (still) cameras, PDA's and PCMCIA cards.

DESCRIPTION

An epitaxial Schottky barrier diode encapsulated in a SOD882 leadless ultra small plastic package.

ESD sensitive device, observe handling precautions.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	5	٧
I _F	continuous forward current		_	20	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms; } \delta = 0.25$	_	400	mA
I _{FSM}	non-repetitive peak forward current	t _p = 8.3 ms half sinewave; JEDEC method	_	550	mA
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

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ELECTRICAL CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	forward voltage	see Fig.2			
		I _F = 0.1 mA	160	200	mV
		I _F = 1 mA	240	300	mV
I _R	continuous reverse current	see Fig.3			
		V _R = 1 V	0.4	1	μΑ
		V _R = 5 V; note 1	_	50	μΑ
C _d	diode capacitance	V _R = 0 V; f = 1 MHz; see Fig.4	0.35	0.5	pF
L _S	series inductance		0.6	_	nH

Note

1. Pulse test: pulse width = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

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Note

1. Refer to SOD882 standard mounting conditions (footprint), FR4 with 60 μm copper strip line.

Soldering

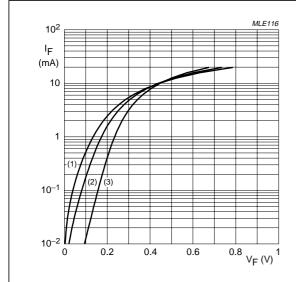
Reflow soldering is the only recommended soldering method.

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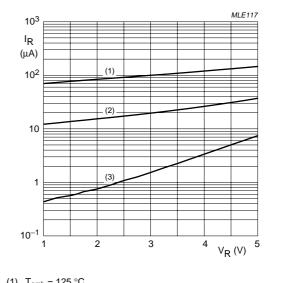
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GRAPHICAL DATA



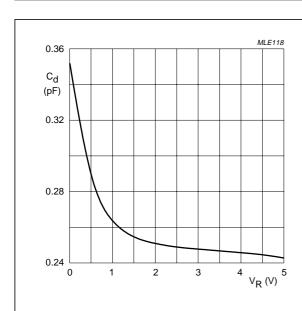
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Reverse current as a function of reverse voltage; typical values.



f = 1 MHz; $T_{amb} = 25 \, ^{\circ}\text{C}$.

Diode capacitance as a function of reverse Fig.4 voltage; typical values.

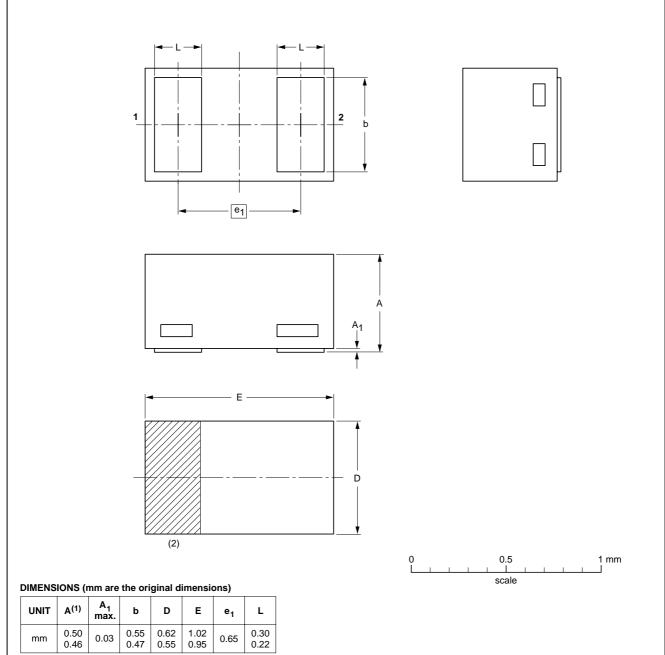
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PACKAGE OUTLINE

Leadless ultra small plastic package; 2 terminals; body 1.0 x 0.6 x 0.5 mm

SOD882



Notes

- 1. Including plating thickness
- 2. The marking bar indicates the cathode

OUTLINE		REFER	ENCES		ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOD882						03-04-16 03-04-17

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
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Notes

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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